#### TOSHIBA THYRISTOR SILICON PLANAR TYPE

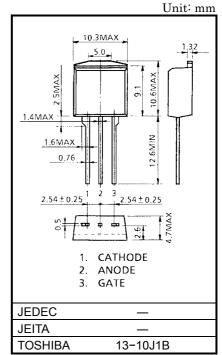
# S6744

### MEDIUM POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : VDRM = 400V Repetitive Peak Reverse Voltage : V<sub>RRM</sub> = 400V
- Average On–State Current  $I_{T}(AV) = 8A$
- A Large Current Pulse Capability •

#### **MAXIMUM RATINGS**

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	V <sub>DRM</sub> V <sub>RRM</sub>	400	V	
Non-Repetitive Peak Reverse Voltage (Non-Repetitive<5ms, Tj = 0~125°C)	V <sub>RSM</sub>	500	V	
Average On-State Current (Half Sine Waveform Tc = 72°C)	I <sub>T (AV)</sub>	8	А	
R.M.S On-State Current	I <sub>T (RMS)</sub>	12.6	А	
Peak One Cycle Surge On-State Current (Non-Repetitive)	ITSM	200 (50Hz)	A	
		220 (60Hz)		
I <sup>2</sup> t Limit Value	l <sup>2</sup> t	200	A <sup>2</sup> s	
Repetitive Peak Surge On-State Current (Note 1)	I <sub>TRM</sub>	1300	А	
Critical Rate of Rise of On-State Current (Note 2)	di / dt	100	A / µs	
Peak Gate Power Dissipation	P <sub>GM</sub>	5	W	
Average Gate Power Dissipation	P <sub>G (AV)</sub>	0.5	W	
Peak Forward Gate Voltage	V <sub>FGM</sub>	10	V	
Peak Reverse Gate Voltage	V <sub>RGM</sub>	-5	V	
Peak Forward Gate Current	I <sub>GM</sub>	2	А	
Junction Temperature	Tj	-40~125	°C	
Storage Temperature Range	T <sub>stg</sub>	-40~125	°C	



Weight: 1.7 g

Note 1:  $C_M \le 500 \mu$ F,  $t_W \le 300 \mu$ s,  $V_D \le 350 V$ 

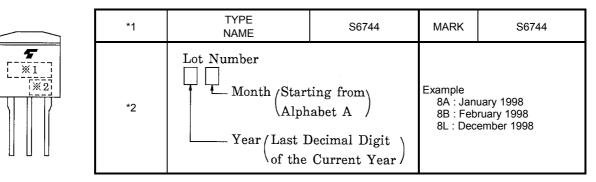
Note 2: di / dt Test condition

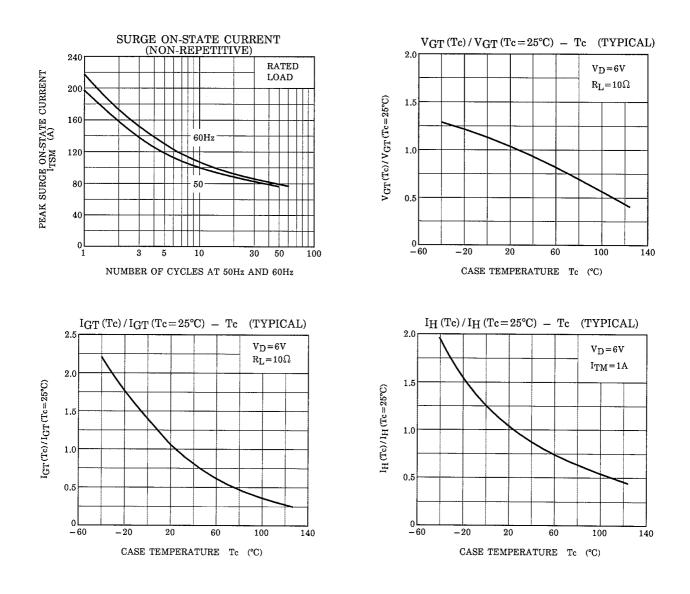
V<sub>DRM</sub> = 0.5 × Rated, I<sub>TM</sub> ≤ 25A, t<sub>gw</sub> ≥ 10µs, t<sub>gr</sub> ≤ 250ns, i<sub>gp</sub> = I<sub>GT</sub> × 2.0

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>DRM</sub> = V <sub>RRM</sub> = Rated	_	_	10	μA
Peak On-State Voltage	V <sub>TM</sub>	I <sub>TM</sub> = 25A		_	1.5	V
Gate Trigger Voltage	V <sub>GT</sub>	V <sub>D</sub> = 6V, R <sub>I</sub> = 10Ω		-	1.0	V
Gate Trigger Current	I <sub>GT</sub>	$v_{\rm D} = 0v, \kappa_{\rm L} = 10\Omega$	_	_	20	mA
Gate Non-Trigger Voltage	V <sub>GD</sub>	V <sub>D</sub> = Rated × 2 / 3, Tc = 125°C	0.2	_	_	V
Critical Rate of Rise of Off-State Voltage	dv / dt	V <sub>DRM</sub> = Rated,Tc = 125°C, Exponential Rise	_	50	_	V / µs
Holding Current	Ι <sub>Η</sub>	V <sub>D</sub> = 6V, I <sub>TM</sub> = 1A		_	40	mA
Latching Current	١L	V <sub>D</sub> = 6V, f = 50Hz, t <sub>gw</sub> = 100µs, i <sub>G</sub> = 40mA	_	_	60	mA
Thermal Resistance	R <sub>th (j−a)</sub>	Junction to Ambient	_	_	70	°C/W

#### MARKING





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